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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







CBT3126

Quad FET bus switch Rev. 04 — 12 October 2009

Product data sheet

General description 1.

The CBT3126 is a quad FET bus switch with independent line switches. Each switch is disabled when the associated Output Enable (OE) input is LOW.

The CBT3126 is characterized for operation from -40 °C to +85 °C.

Features 2.

- Standard '126-type pinout
- Multiple package options
- \blacksquare 5 Ω switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- Latch-up protection exceeds 500 mA per JEDEC standard JESD78 class II level A
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101C exceeds 1000 V
- Specified from -40 °C to +85 °C

Ordering information 3.

Table 1. **Ordering information**

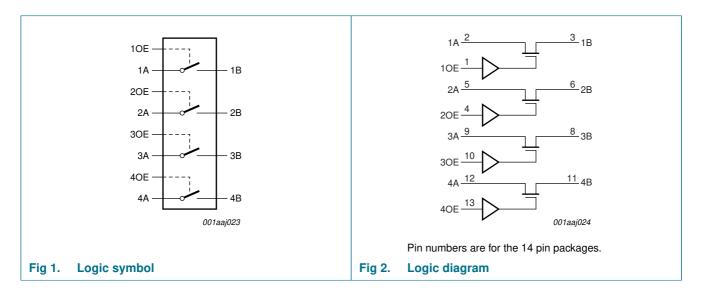
Type number	Temperature range	Package							
		Name	Description	Version					
CBT3126D	–40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1					
CBT3126DB	–40 °C to +85 °C	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1					
CBT3126PW	–40 °C to +85 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1					
CBT3126DS	–40 °C to +85 °C	SSOP16[1]	plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm	SOT519-1					

[1] Also known as QSOP16.



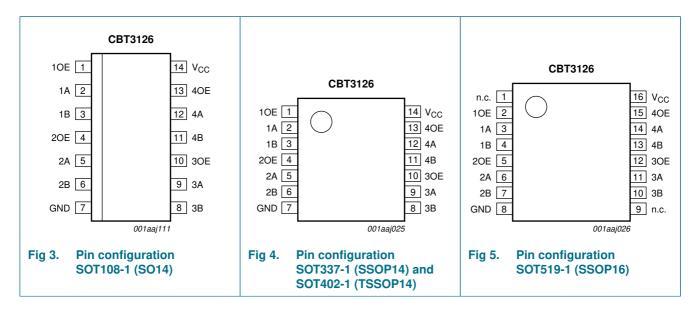
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4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Pin						
	SOT108-1 SOT337-1 and SOT402-1	SOT519-1						
10E to 40E	1, 4, 10, 13	2, 5, 12, 15	output enable input					
1A to 4A,	2, 5, 9, 12	3, 6, 11, 14	A input/output					
1B to 4B	3, 6, 8, 11	4, 7, 10, 13	B output/input					

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Table 2. Pin description ...continued

Symbol	Pin		Description
	SOT108-1 SOT337-1 and SOT402-1	SOT519-1	
GND	7	8	ground (0 V)
V _{CC}	14	16	positive supply voltage
n.c.	-	1, 9	not connected

6. Functional description

Table 3. Function selection

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Inputs	Switch
nOE	
L	nA to nB disconnected
Н	nA to nB connected

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
V_{I}	input voltage		<u>[1]</u> –0.5	+7.0	V
I_{SW}	switch current	continuous current through each switch	-	128	mA
I _{IK}	input clamping current	$V_I < 0 V$	-50	-	mA
T _{stg}	storage temperature		–65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	<u>[2]</u>		
		SO14 package	<u>[3]</u> _	500	mW
		SSOP14 and SSOP16 package	<u>[4]</u> _	500	mW
		TSSOP14 package	<u>[4]</u> _	500	mW

^[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

8. Recommended operating conditions

Table 5. Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		4.5	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	V
V_{IL}	LOW-level input voltage		-	8.0	V
T _{amb}	ambient temperature	operating in free-air	-40	+85	°C

^[2] The package thermal impedance is calculated from JESD51-7.

^[3] For SO14 package; P_{tot} derates linearly with 8 mW/K above 70 °C.

^[4] For SSOP14, SSOP16 and TSSOP14 packages; P_{tot} derates linearly with 5.5 mW/K above 70 $^{\circ}$ C.

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9. Static characteristics

Table 6. Static characteristics

 $T_{amb} = -40 \,^{\circ}C$ to $+85 \,^{\circ}C$.

Parameter	Conditions	Min	Tyn[1]	May	Unit
		141111	ı y P		
input clamping voltage	$V_{CC} = 4.5 \text{ V}; I_{I} = -18 \text{ mA}$	-	-	-1.2	V
pass voltage	$V_I = V_{CC} = 5.0 \ V; \ I_{SW} = -100 \ \mu A$	-	3.8	-	V
input leakage current	V_{CC} = 5.5 V; V_I = GND or 5.5 V	-	-	±1	μΑ
supply current	V_{CC} = 5.5 V; I_{SW} = 0 mA; V_I = V_{CC} or GND	-	-	3	μΑ
additional supply current	control pins; per input; $V_{CC} = 5.5 \text{ V}$; one input at 3.4 V, other inputs at V_{CC} or GND	[2] -	-	2.5	mA
input capacitance	control pins; V _I = 3 V or 0 V	-	1.7	-	рF
off-state input/output capacitance	$V_O = 3 \text{ V or } 0 \text{ V}; \text{ nOE} = V_{CC}$	-	3.4	-	рF
ON resistance	$V_{CC} = 4.0 \text{ V}$	[3]			
	$V_I = 2.4 \text{ V}; I_I = 15 \text{ mA}$	-	16	22	Ω
	V _{CC} = 4.5 V			3 μA 2.5 mA - pF - pF	
	$V_I = 0 \ V; \ I_I = 64 \ mA$	-	5	7	Ω
	$V_{I} = 0 \ V; \ I_{I} = 30 \ mA$	-	5	7	Ω
	$V_{I} = 2.4 \text{ V}; I_{I} = 15 \text{ mA}$	-	10	15	Ω
	input leakage current supply current additional supply current input capacitance off-state input/output capacitance	$\begin{array}{lll} \text{input clamping voltage} & V_{CC} = 4.5 \text{ V; } I_{I} = -18 \text{ mA} \\ \\ \text{pass voltage} & V_{I} = V_{CC} = 5.0 \text{ V; } I_{SW} = -100 \mu\text{A} \\ \\ \text{input leakage current} & V_{CC} = 5.5 \text{ V; } V_{I} = \text{GND or } 5.5 \text{ V} \\ \\ \text{supply current} & V_{CC} = 5.5 \text{ V; } I_{SW} = 0 \text{ mA; } \\ V_{I} = V_{CC} \text{ or GND} \\ \\ \text{additional supply current} & \text{control pins; per input; } \\ V_{CC} = 5.5 \text{ V; one input at } 3.4 \text{ V, other inputs at } V_{CC} \text{ or GND} \\ \\ \text{input capacitance} & \text{control pins; } V_{I} = 3 \text{ V or } 0 \text{ V} \\ \\ \text{off-state input/output capacitance} & V_{O} = 3 \text{ V or } 0 \text{ V; nOE} = V_{CC} \\ \\ \text{ON resistance} & V_{CC} = 4.0 \text{ V} \\ \\ \hline V_{I} = 2.4 \text{ V; } I_{I} = 15 \text{ mA} \\ \\ \hline V_{CC} = 4.5 \text{ V} \\ \\ \hline V_{I} = 0 \text{ V; } I_{I} = 64 \text{ mA} \\ \\ \hline V_{I} = 0 \text{ V; } I_{I} = 30 \text{ mA} \\ \\ \hline \end{array}$	$\begin{array}{c} \text{input clamping voltage} & V_{CC} = 4.5 \text{ V; } I_{I} = -18 \text{ mA} \\ \\ \text{pass voltage} & V_{I} = V_{CC} = 5.0 \text{ V; } I_{SW} = -100 \mu\text{A} \\ \\ \text{input leakage current} & V_{CC} = 5.5 \text{ V; } V_{I} = \text{GND or } 5.5 \text{ V} \\ \\ \text{supply current} & V_{CC} = 5.5 \text{ V; } I_{SW} = 0 \text{ mA; } \\ V_{I} = V_{CC} \text{ or GND} \\ \\ \text{additional supply current} & \text{control pins; per input; } \\ V_{CC} = 5.5 \text{ V; one input at } 3.4 \text{ V, other inputs at } V_{CC} \text{ or GND} \\ \\ \text{input capacitance} & \text{control pins; } V_{I} = 3 \text{ V or } 0 \text{ V} \\ \\ \text{off-state input/output capacitance} & V_{O} = 3 \text{ V or } 0 \text{ V; nOE} = V_{CC} \\ \\ \text{ON resistance} & V_{CC} = 4.0 \text{ V} \\ \\ \hline V_{I} = 2.4 \text{ V; } I_{I} = 15 \text{ mA} \\ \\ \hline V_{CC} = 4.5 \text{ V} \\ \\ \hline V_{I} = 0 \text{ V; } I_{I} = 64 \text{ mA} \\ \\ \hline V_{I} = 0 \text{ V; } I_{I} = 30 \text{ mA} \\ \\ \end{array} - \\ \hline \end{array}$	input clamping voltage $V_{CC} = 4.5 \text{ V}; \text{ I}_{I} = -18 \text{ mA} \qquad - \qquad $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

^[1] All typical values are measured at V_{CC} = 5 V; T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

 T_{amb} = -40 °C to +85 °C; V_{CC} = 4.5 V to 5.5 V; for test circuit see Figure 8.

Symbol	Parameter	Conditions	Min	Max	Unit
t_{pd}	propagation delay	nA to nB or nB to nA; see Figure 6	[1][2]	0.25	ns
t _{en}	enable time	nOE to nA or nB; see Figure 7	<u>[2]</u> 1.6	4.5	ns
t _{dis}	disable time	nOE to nA or nB; see Figure 7	<u>[2]</u> 1.0	5.4	ns

^[1] This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON resistance of the switch and a load capacitance, when driven by an ideal voltage source (zero output impedance).

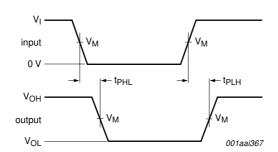
[2] t_{PLH} and t_{PHL} are the same as t_{pd} ; t_{PZL} and t_{PZH} are the same as t_{en} ; t_{PLZ} and t_{PHZ} are the same as t_{dis} .

^[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

^[3] Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. ON resistance is determined by the lowest voltage of the two (A or B) terminals.

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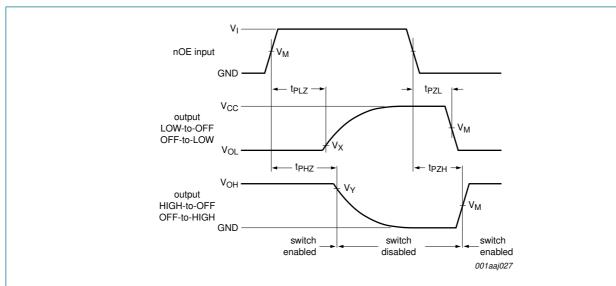
11. AC waveforms



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. The input (nA, nB) to output (nB, nA) propagation delay times



Measurement points are given in Table 8.

 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical voltage output levels that occur with the output load.

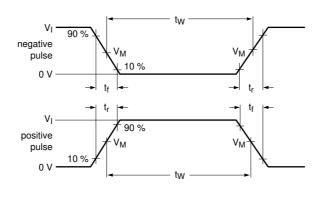
Fig 7. Enable and disable times

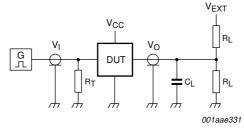
Table 8. Measurement points

Input	Output		
V _M	V _M	V _X	V _Y
1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V

Quad FET bus switch

12. Test information





Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 9. Test data

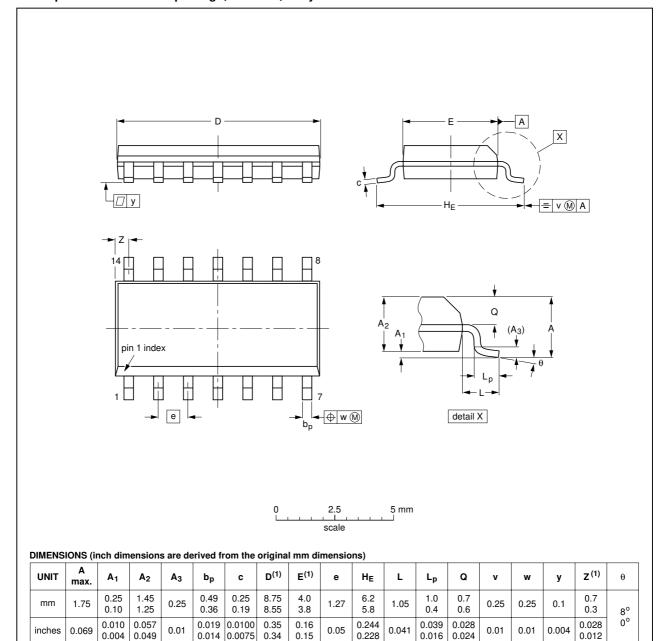
Supply voltage	Input		Load		V _{EXT}			
V _{CC}	V _I t _r , t _f		C _L R _L		t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}	
4.5 V to 5.5 V	GND to 3.0 V ≤ 2.5 ns 5		50 pF 500 Ω		open	7.0 V	open	

Quad FET bus switch

13. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	1550E DATE
SOT108-1	076E06	MS-012			99-12-27 03-02-19

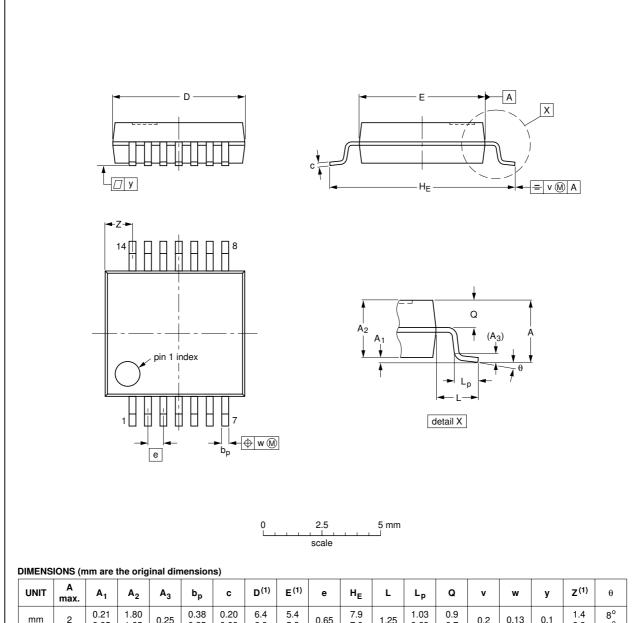
Fig 9. Package outline SOT108-1 (SO14)

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SOT337-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

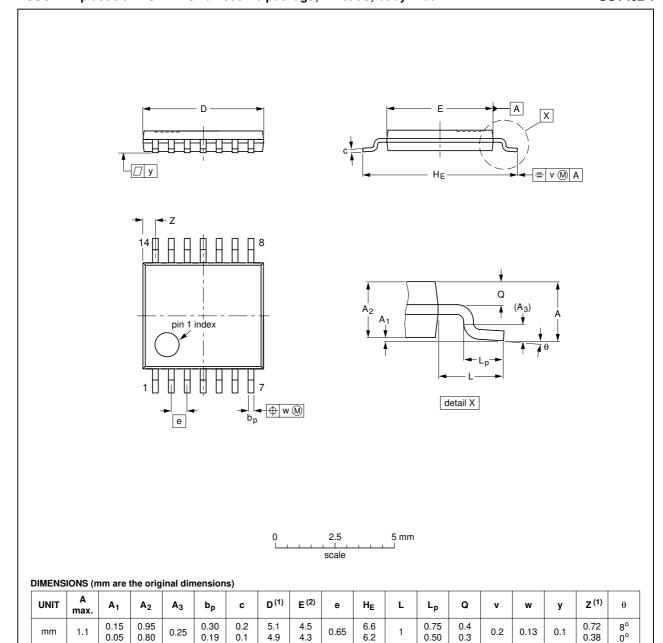
OUTLINE	REFERENCES				EUROPEAN	IOOUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT337-1		MO-150				99-12-27 03-02-19

Fig 10. Package outline SOT337-1 (SSOP14)

Quad FET bus switch

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



NI - 4 - -

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

REFERENCES				EUROPEAN	ISSUE DATE
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	MO-153				99-12-27 03-02-18
-	IEC	IEC JEDEC	IEC JEDEC JEITA	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION

Fig 11. Package outline SOT402-1 (TSSOP14)

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SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

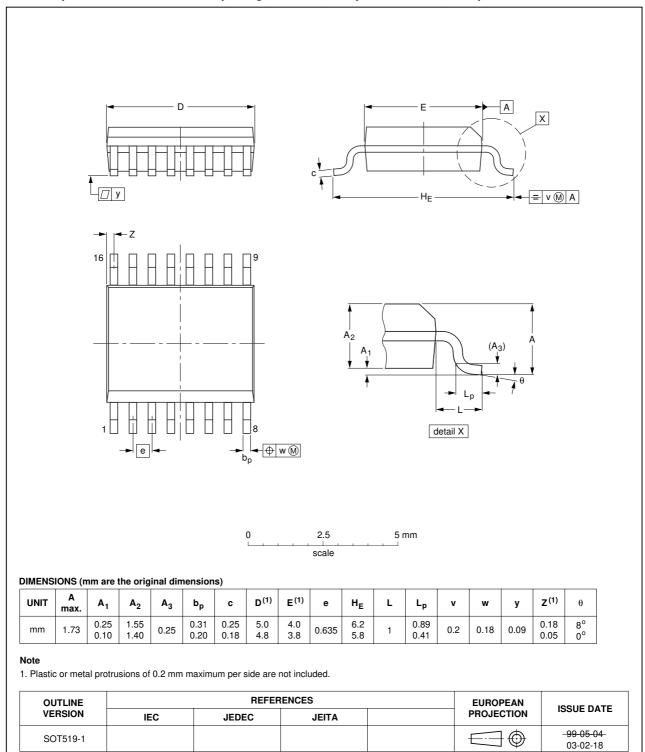


Fig 12. Package outline SOT519-1 (SSOP16)

Quad FET bus switch

14. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CBT3126_4	20091012	Product data sheet	-	CBT3126_3
Modifications:	 Section 7 "Lir 	niting values" changed I_{CC} to I_{S}	SW-	
CBT3126_3	20081209	Product data sheet	-	CBT3126_2
CBT3126_2	20081023	Product data sheet	-	CBT3126_1
CBT3126_1	20011212	Product data sheet	-	-

Quad FET bus switch

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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